# **Surface Mount Schottky Power Rectifier**

# **SMA Power Surface Mount Package**

Employing the Schottky Barrier principle in a large area metal-to-silicon power diode. State of the art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity diodes in surface mount applications where compact size and weight are critical to the system.

#### **Features**

- Small Compact Surface Mountable Package with J-Bent Leads
- Rectangular Package for Automated Handling
- Highly Stable Oxide Passivated Junction
- Low Forward Voltage Drop
- Guardring for Stress Protection
- AEC-Q101 Qualified and PPAP Capable
- NRVBA Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- This is a Pb-Free Device\*

# **Mechanical Characteristics:**

- Case: Epoxy, Molded
- Weight: 70 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Polarity: Cathode Lead Indicated by Polarity Band
- ESD Ratings:
  - ♦ Machine Model = C
  - ♦ Human Body Model = 3B
- Device Meets MSL 1 Requirements



# ON Semiconductor®

http://onsemi.com

# SCHOTTKY BARRIER RECTIFIER 1.0 AMPERES, 100 VOLTS



SMA CASE 403D PLASTIC



#### **MARKING DIAGRAMS**



A110 = Device Code

A = Assembly Location

Y = Year WW = Work Week = Pb-Free Package

# ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
MBRA1H100T3G	SMA (Pb-Free)	5,000 / Tape & Reel **
NRVBA1H100T3G	SMA (Pb-Free)	5,000 / Tape & Reel **

<sup>\*\* 12</sup> mm Tape, 13" Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	100	V
Average Rectified Forward Current $(T_L = 167^{\circ}C)$	I <sub>O</sub>	1.0	Α
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I <sub>FSM</sub>	50	Α
Storage and Operating Junction Temperature Range (Note 1)	T <sub>stg</sub> , T <sub>J</sub>	-65 to +175	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Lead (Note 2)	$\Psi_{JCL}$	14	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	75	°C/W
Thermal Resistance, Junction-to-Ambient (Note 3)	$R_{\theta JA}$	280	°C/W

<sup>2.</sup> Mounted with 700 mm<sup>2</sup> copper pad size (Approximately 1 in<sup>2</sup>) 1 oz FR4 Board.

## **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 4)	V <sub>F</sub>	0.76 0.84 0.61 0.68	V
Maximum Instantaneous Reverse Current (Note 4) (Rated dc Voltage, T <sub>J</sub> = 25°C) (Rated dc Voltage, T <sub>J</sub> = 125°C)	I <sub>R</sub>	40 0.5	μA mA

<sup>4.</sup> Pulse Test: Pulse Width ≤ 380 μs, Duty Cycle ≤ 2.0%.

<sup>1.</sup> The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

<sup>3.</sup> Mounted with pad size approximately 6 mm<sup>2</sup> copper, 1 oz FR4 Board.

#### **TYPICAL CHARACTERISTICS**

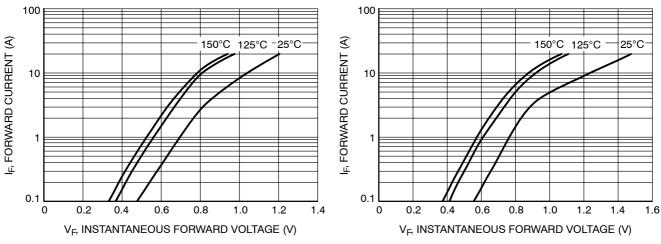
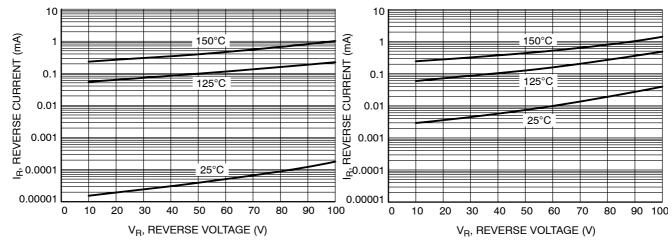


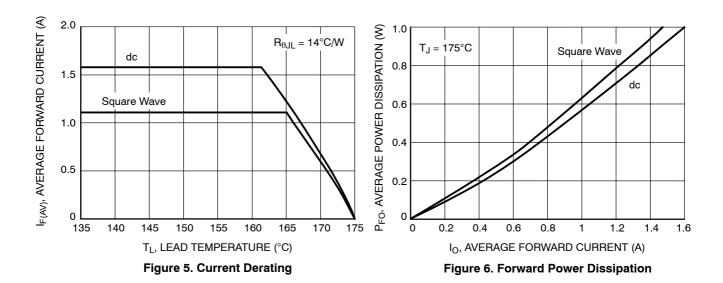
Figure 1. Typical Forward Voltage

Figure 2. Maximum Forward Voltage



**Figure 3. Typical Reverse Current** 

**Figure 4. Maximum Reverse Current** 



#### **TYPICAL CHARACTERISTICS**

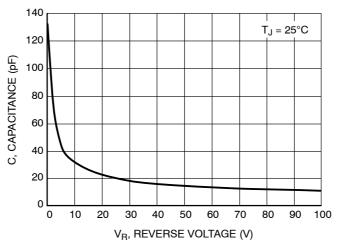


Figure 7. Capacitance

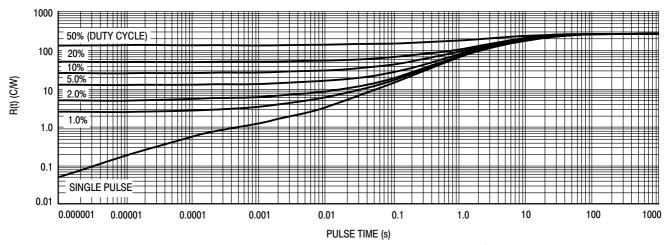


Figure 8. Thermal Response, Junction-to-Ambient (6 mm<sup>2</sup> pad)

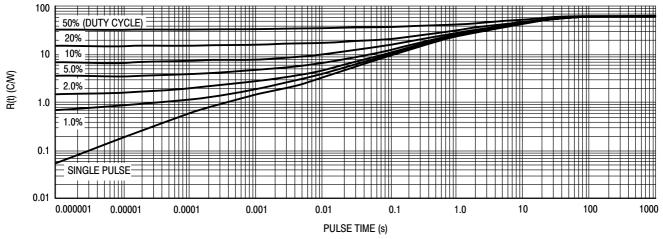
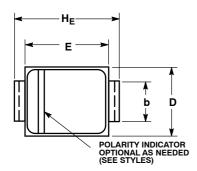


Figure 9. Thermal Response, Junction-to-Ambient (1 in<sup>2</sup> pad)

#### PACKAGE DIMENSIONS

# **SMA**

CASE 403D-02 **ISSUE F** 



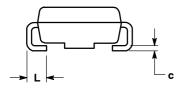


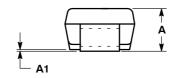
- 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- 403D-01 OBSOLETE, NEW STANDARD IS 403D-02.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.97	2.10	2.20	0.078	0.083	0.087
A1	0.05	0.10	0.15	0.002	0.004	0.006
b	1.27	1.45	1.63	0.050	0.057	0.064
С	0.15	0.28	0.41	0.006	0.011	0.016
D	2.29	2.60	2.92	0.090	0.103	0.115
E	4.06	4.32	4.57	0.160	0.170	0.180
HE	4.83	5.21	5.59	0.190	0.205	0.220
L	0.76	1.14	1.52	0.030	0.045	0.060

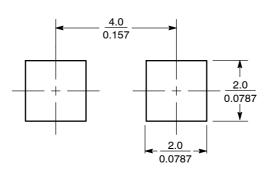


PIN 1. CATHODE (POLARITY BAND) 2. ANODE





#### **SOLDERING FOOTPRINT\***



mm SCALE 8:1

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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